



SOD-523 Surface Mounted Zener Diode 表面贴装稳压二极管

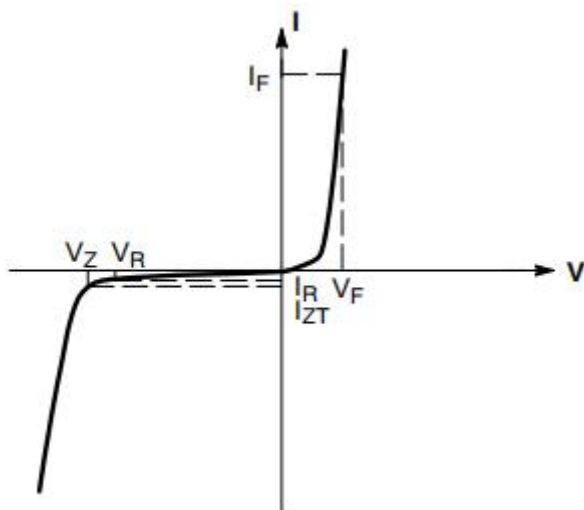


■SOD-523 Internal Configuration 内部结构



■Features 特点

Characteristic 特性参数	Symbol 符号	Max 最大值	Unit 单位
Power dissipation 耗散功率	P_D ($T_a=25^{\circ}\text{C}$)	200	mW
Forward Current 正向电流	I_F	250	mA
Forward Voltage 正向电压	V_F (@ $I_F=10\text{mA}$)	0.9	V
Reverse Voltage 反向电压	V_Z	2.4-75	V
Junction and Storage Temperature 结温和储藏温度	T_J, T_{stg}	125 $^{\circ}\text{C}$, -55to+125 $^{\circ}\text{C}$	





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BZX584C2V4-6AF~BZX584C75-6AF

■ Electrical Characteristics 电特性

($T_A=25^{\circ}\text{C}$ unless otherwise noted 如无特殊说明, 温度为 25°C)

Type	V _Z (V)		DIFFERENTIAL RESISTANCE r _{diff} (Ω)				TEMP. COEFF. S _Z (mV/K)			I _R (uA)		Mark ing
	@I _Z =5mA		@I _Z =1mA		@I _Z =5mA		@I _Z =5mA			@V _R (V)		
	MIN.	MAX.	TYP.	MAX.	TYP.	MAX.	MIN.	TYP.	MAX.	I _R	@V _R	
BZX584C2V4-6AF	2.2	2.6	325	600	80	100	-3.5	-2.1	0	50	1	Z11
BZX584C2V7-6AF	2.5	2.9	325	600	80	100	-3.5	-2.1	0	20	1	Z12
BZX584C3V0-6AF	2.8	3.2	325	600	80	95	-3.5	-2.1	0	10	1	Z13
BZX584C3V3-6AF	3.1	3.5	350	600	85	95	-3.5	-2.4	0	5	1	Z14
BZX584C3V6-6AF	3.4	3.8	375	600	85	90	-3.5	-2.4	0	5	1	Z15
BZX584C3V9-6AF	3.7	4.1	400	600	85	90	-3.5	-2.5	0	3	1	Z16
BZX584C4V3-6AF	4.0	4.6	400	600	85	90	-3.5	-2.5	0	3	1	Z17
BZX584C4V7-6AF	4.4	5.0	410	600	80	90	-3.5	-2.5	0	3	2	Z1
BZX584C5V1-6AF	4.8	5.4	425	500	50	80	-3.5	-1.4	0.2	2	2	Z2
BZX584C5V6-6AF	5.2	6.0	400	480	40	60	-2.7	-0.8	1.2	1	2	Z3
BZX584C6V2-6AF	5.8	6.6	80	400	15	40	-2.0	1.2	2.5	3	4	Z4
BZX584C6V8-6AF	6.4	7.2	40	150	6	10	0.4	2.3	3.7	2	4	Z5
BZX584C7V5-6AF	7.0	7.9	30	80	6	15	1.2	3.0	4.5	1	5	Z6
BZX584C8V2-6AF	7.7	8.7	30	80	6	15	2.5	4.0	5.3	0.7	5	Z7
BZX584C9V1-6AF	8.5	9.6	40	80	6	15	3.2	4.6	6.2	0.5	6	Z8
BZX584C10-6AF	9.4	10.6	40	100	6	15	3.8	5.5	7.0	0.2	7	Z9
BZX584C11-6AF	10.4	11.6	50	150	8	20	4.5	6.4	8.0	0.1	8	Y1
BZX584C12-6AF	11.4	12.7	50	150	10	20	5.4	7.4	9.0	0.1	8	Y2
BZX584C13-6AF	12.4	14.1	50	150	10	25	6.0	8.4	10.0	0.1	8	Y3
BZX584C15-6AF	13.8	15.6	50	170	10	30	7.0	9.4	11.0	0.05	10.	Y4
BZX584C16-6AF	15.3	17.1	50	200	10	30	9.2	11.4	13.0	0.05	11.	Y5
BZX584C18-6AF	16.8	19.1	50	200	10	40	10.4	12.4	14.0	0.05	12.	Y6
BZX584C20-6AF	18.8	21.2	50	225	10	45	12.4	14.4	16.0	0.05	14	Y7
BZX584C22-6AF	20.8	23.3	60	225	15	55	14.4	16.4	18.0	0.05	15.	Y8
BZX584C24-6AF	22.8	25.6	60	250	20	55	16.4	18.4	20.0	0.05	16.	Y9
	@I _Z =2mA		@I _Z =0.5mA		@I _Z =2mA		@I _Z =2mA					
BZX584C27-6AF	25.1	28.9	65	300	25	80	21.4	23.4	25.3	0.05	18.	Y10
BZX584C30-6AF	28.0	32.0	70	300	30	80	24.4	26.6	29.4	0.05	21	Y11
BZX584C33-6AF	31.0	35.0	75	325	35	80	27.4	29.7	33.4	0.05	23.	Y12
BZX584C36-6AF	34.0	38.0	80	350	35	90	30.4	33.0	37.4	0.05	25.	Y13
BZX584C39-6AF	37.0	41.0	80	350	40	130	33.4	36.4	41.2	0.05	27.	Y14
BZX584C43-6AF	40.0	46.0	85	375	45	150	37.6	41.2	46.6	0.05	30.	Y15
BZX584C47-6AF	44.0	50.0	85	375	50	170	42.0	46.1	51.8	0.05	32.	Y16
BZX584C51-6AF	48.0	54.0	95	400	60	180	46.6	51.3	57.2	0.05	35.	Y17
BZX584C56-6AF	52.0	60.0	110	425	75	200	52.2	58.4	63.8	0.05	39.	Y18
BZX584C62-6AF	58.0	66.0	130	450	90	215	58.8	63.9	71.6	0.05	43.	Y19
BZX584C68-6AF	64.0	72.0	160	475	110	240	65.	72.2	79.8	0.05	47.	Y20
BZX584C75-6AF	70.0	79.0	200	500	150	255	73.	81.1	88.6	0.05	52.	Y21

■ Typical Characteristic Curve 典型特性曲线

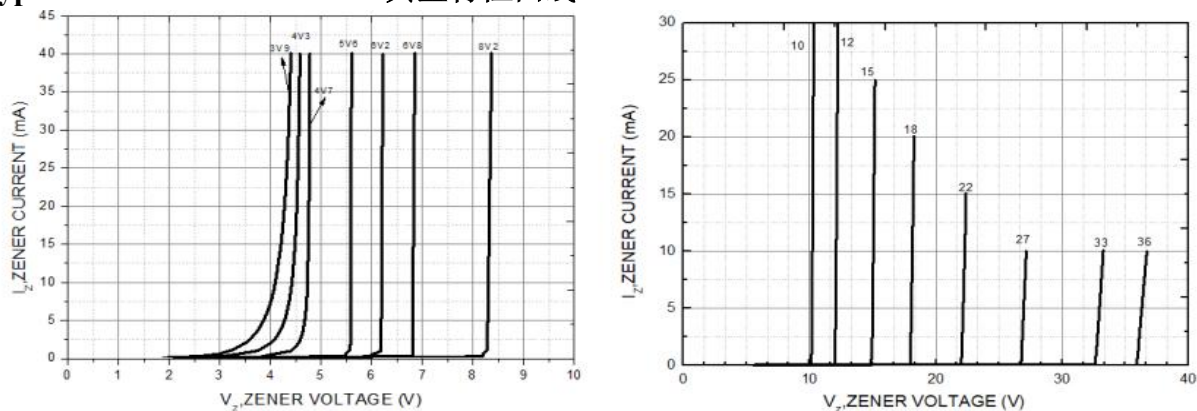


Figure 1: Zener Characteristics

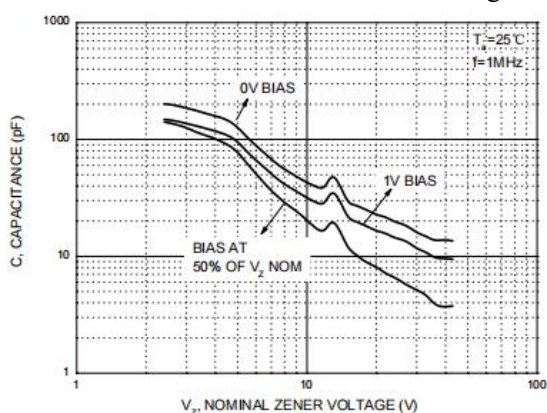


Figure 2: Capacitance Characteristics

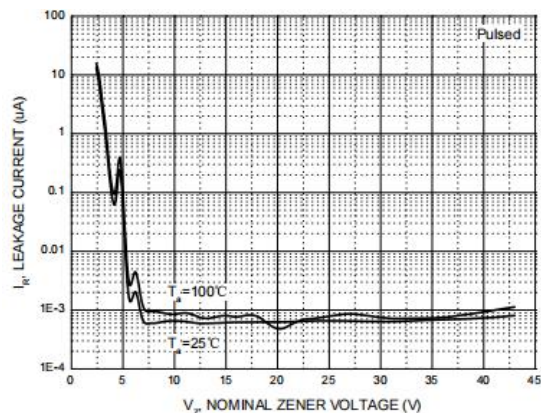


Figure 3: Leakage Current

■ Dimension 外形封装尺寸

